



## SINGLE CHANNEL SMART LOAD SWITCH

## **Description and Applications**

The DML1010FDK is a single channel load switch with very low onresistance in a small package. It contains an N-channel MOSFET for up to V<sub>VBIAS</sub>-1.5V input voltage operation and 6A current channel with 3.2V to 5.5V bias supply. The load switch is controlled by a low voltage control signal through ON pin.

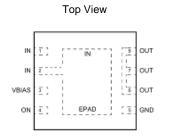
## **Features and Benefits**

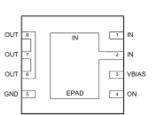
- Low RDS(ON)-Ensures On State Losses Are Minimized
- 0.8V to V<sub>VBIAS</sub>-1.5V Input Voltage Range
- 6A Continuous Current
- Low R<sub>DS(ON)</sub> Internal NFETs
  - $8m\Omega$  at  $V_{BIAS} = 5V$ ,  $V_{IN} = 1.05V$ ,  $T_A = +85^{\circ}C$
- 35µA Low Quiescent Current
- 10µs Turn On Rise Time
- 3.2V to 5.5V Bias Voltage
- Integrated Quick Output Discharge Resistor
- Moisture Sensitivity: Level 1 per J-STD-020
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

## Applications

- Portable Electronics and Systems
- Notebook and Tablet Computers
- Telecom, Networking, Medical, and Industrial Equipment
- Set-Top Boxes, Servers, and Gateways
- SSD

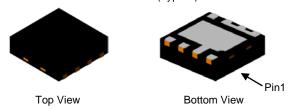
## **Pin Assignments**





Bottom View

#### U-DFN2020-8 (Type K)



## Ordering Information (Note 4)

	Part Number	Case	Packaging			
	DML1010FDK-7	U-DFN2020-8 (Type K)	3000/Tape & Reel			
Notes:	1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

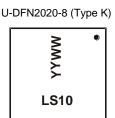
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

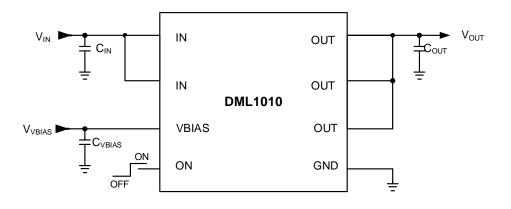
## **Marking Information**



LS10 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)



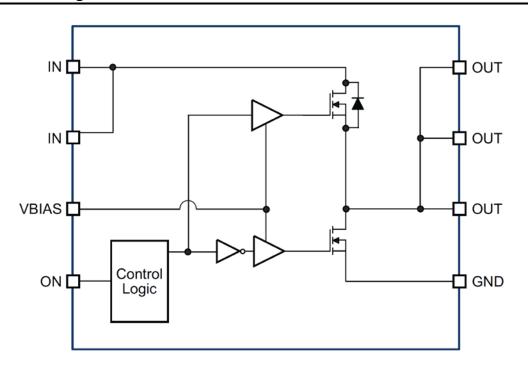
## **Typical Application Circuit**



## **Pin Description**

Pin Number	Pin Name	Pin Function
1, 2, EPAD	IN	Load Switch Input. Bypass capacitor is recommended to minimize input voltage dip.
3	VBIAS	Bias Voltage. Power supply input for the device.
4	ON	Enable Input. Load switch is on when ON is pulled high. Load switch is off when ON is pulled low. Do not leave floating.
5	GND	Ground.
6, 7, 8	OUT	Load switch output.

## **Function Block Diagram**





## **Absolute Maximum Rating**

Parameter	Rating
IN, ON, VBIAS, OUT to GND	-0.3V to 6V
Junction Temperature (T <sub>J</sub> )	+150°C
I <sub>MAX</sub>	12A
Storage Temperature (T <sub>S</sub> )	-65°C to +150°C
ESD Rating HBM/CDM	2kV/1kV

## **Recommended Operating Ranges**

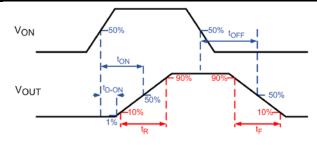
Parameter	Rating		
Supply Voltage (V <sub>VBIAS</sub> )	3.2V to 5.5V		
Input Voltage (V <sub>IN</sub> )	0.8V to $V_{\text{BIAS}}\text{-}1.5\text{V}$		
Ambient Temperature (T <sub>A</sub> )	-40°C to +85°C		
Package Thermal Resistance ( $\Theta_{JC}$ )	8°C/W		
Package Thermal Resistance ( $\Theta_{JA}$ )	60°C/W		

## **Electrical Characteristics** ( $T_A = +25^{\circ}C$ , $V_{VBIAS}=5V$ , $V_{IN}=1.05V$ , unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
VIN	IN Supply Voltage	$V_{ON} = 5V$	0.8	1.05	V <sub>VBIAS</sub> -1.5	V
VVBIAS	VBIAS Supply Voltage	—	3.2	5	5.5	V
ID	Maximum Continuous Current	$V_{ON} = 5V$	_	6	—	А
I <sub>PLS</sub>	Maximum Pulsed Switch Current	V <sub>IN</sub> = V <sub>ON</sub> = 5V Pulse < 300µs, 2% Duty Cycle	_	9		А
lq	Quiescent Supply Current of VBIAS	$I_{OUT} = 0V, V_{ON} = 5V$	_	35	—	μA
IOFF	VBIAS Shutdown Supply Current	$V_{ON} = 0V, V_{OUT} = 0V$	_	—	2	μA
IINOFF	IN Shutdown Supply Current	$V_{ON} = 0V, V_{OUT} = 0V$		_	2	μA
ION	ON Leakage Current	$V_{ON} = 5V$		_	1	μA
Vonh	ON High Level Voltage	—	1.2	—	—	V
Vonl	ON Low Level Voltage	—	_	—	0.5	V
Switching	ON Resistance			•		
		$I_{OUT} = -200 \text{mA}, V_{ON} = 5 \text{V}, V_{VBIAS} = 5 \text{V}$	—	—	8	mΩ
R <sub>ON</sub>	Switch ON-State Resistance	$I_{OUT}$ = -200mA, $V_{ON}$ = 5V, $V_{VBIAS}$ = 3.3V	_	_	10	mΩ
R <sub>PD</sub>	Output Pull-Down Resistance	$I_{OUT} = 15 \text{mA}, V_{ON} = 0 \text{V}$	_	_	200	Ω

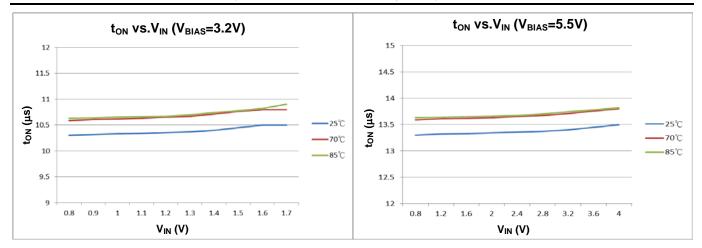
# **Switching Electrical Characteristics** ( $T_A = +25^{\circ}C$ , $V_{VBIAS}=V_{ON}=5V$ , $V_{IN}=1.05V$ , $C_{IN}=1\mu$ F, $C_{OUT}=0.1\mu$ F, unless otherwise specified.)

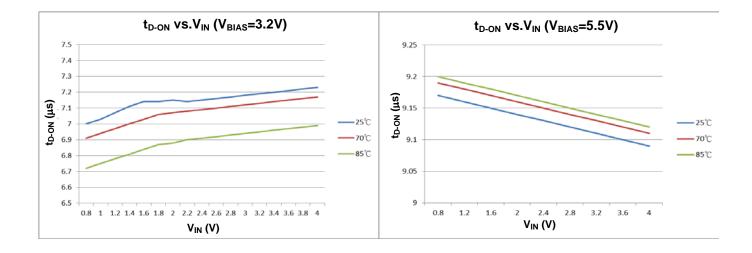
Symbol	Parameter	Min	Тур	Max	Unit
V <sub>IN</sub> = 1.5V	, $V_{VBIAS} = V_{ON} = 5V$				
t <sub>ON</sub>	Turn-ON Time	10	—	65	
t <sub>D-ON</sub>	Turn-ON Delay time	7.5	—	45	
t <sub>R</sub>	Turn-ON Rise Time	5	_	33	μs
t <sub>OFF</sub>	Turn-OFF Time	_	0.2	—	
t <sub>F</sub>	Turn-OFF Fall Time	—	0.7	—	
V <sub>IN</sub> = 1.05	$V, V_{VBIAS} = V_{ON} = 5V$				
t <sub>ON</sub>	Turn-ON Time	10	_	65	
t <sub>D-ON</sub>	Turn-ON Delay time	7.5	—	45	
t <sub>R</sub>	Turn-ON Rise Time	5	—	33	μs
t <sub>OFF</sub>	Turn-OFF Time	—	0.2	—	1
tF	Turn-OFF Fall Time	_	0.7	_	1

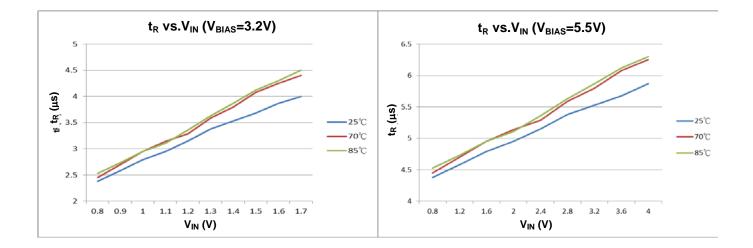




#### Performance Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

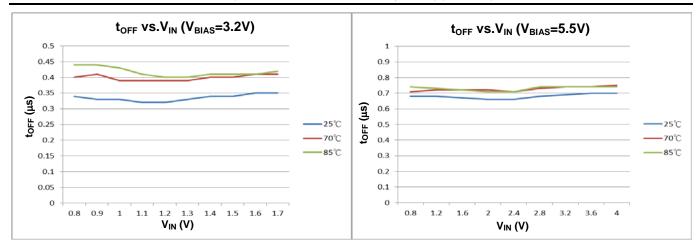


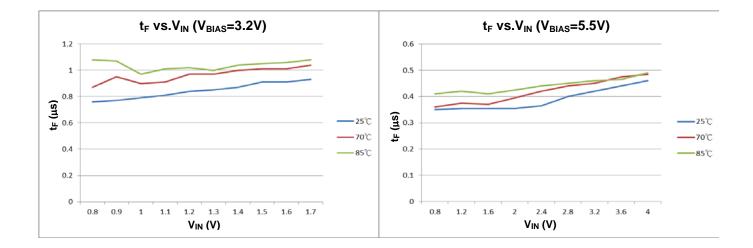






#### Performance Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.) (continued)



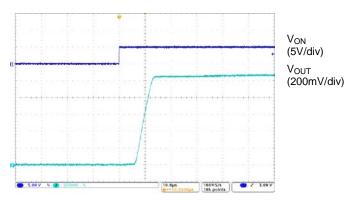




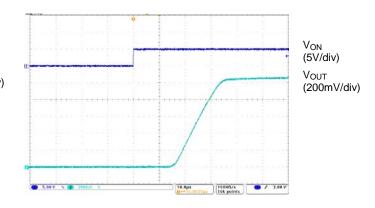
## Performance Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified) (continued)

#### Turn-ON & Turn-ON Rise Times

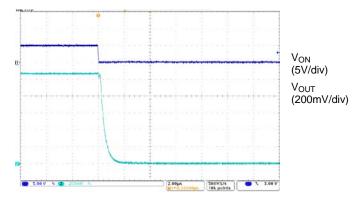
 $V_{\text{IN}}\text{=}1.05V, \, V_{\text{VBIAS}}\text{=}5V, \, C_{\text{IN}}\text{=}1\mu F, \, C_{\text{OUT}}\text{=}0.1\mu F, \, R_{\text{OUT}}\text{=}10\Omega$ 



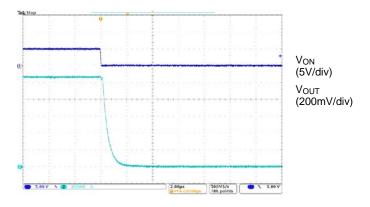
## Turn-ON & Turn-ON Rise Times $V_{IN}$ =1.05V, $V_{VBIAS}$ =3.2V, $C_{IN}$ =1 $\mu$ F, $C_{OUT}$ =0.1 $\mu$ F, $R_{OUT}$ =10 $\Omega$



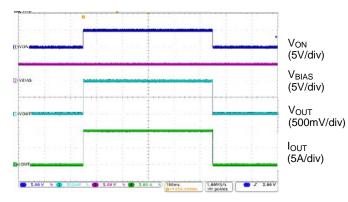
 $\label{eq:VIN} \begin{array}{l} \textbf{Turn-OFF \& Turn-OFF FALL Times} \\ V_{\text{IN}} = 1.05 V, \ V_{\text{VBIAS}} = 5 V, \ C_{\text{IN}} = 1 \mu F, \ C_{\text{OUT}} = 0.1 \mu F, \ R_{\text{OUT}} = 10 \Omega \end{array}$ 



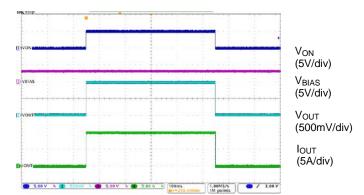
 $\label{eq:VIN} \begin{array}{l} \textbf{Turn-OFF \& Turn-OFF FALL Times} \\ V_{\text{IN}} = 1.05 V, \, V_{\text{VBIAS}} = 3.2 V, \, C_{\text{IN}} = 1 \mu F, \, C_{\text{OUT}} = 0.1 \mu F, \, R_{\text{OUT}} = 10 \Omega \end{array}$ 



Turn-ON & Turn-OFF at I<sub>out</sub>= -10A V<sub>IN</sub>=1.05V, V<sub>VBIAS</sub>=5V, C<sub>IN</sub>=1µF, C<sub>OUT</sub>=0.1µF, R<sub>OUT</sub>=0.1Ω



Turn-ON & Turn-OFF at I<sub>out</sub>= -10A V<sub>IN</sub>=1.05V, V<sub>VBIAS</sub>=3.2V, C<sub>IN</sub>=1µF, C<sub>OUT</sub>=0.1µF, R<sub>OUT</sub>=0.1Ω





## **Application Information**

#### **General Description**

The DML1010FDK is a single-channel, 6A load switch in an 8-pin DFN20x20 package. To reduce the voltage drop in high current rails, the device implements an ultra-low resistance N-channel MOSFET, which can be operated input voltage range from 0.8V to 3.5V.

The device has very low leakage current during off state. This prevents downstream circuits from pulling high standby current from the supply. Integrated control logic, driver, power supply and discharge FET eliminates the requirement for any external components, which reduce solution size and bill of materials (BOM) count.

#### **Enable Control**

The DML1010FDK device allows for enabling the MOSFET in an active-high configuration. When the VBIAS supply pin has an adequate voltage applied and the ON pin is at logic high level, the MOSFET is enabled. Similarly, when the ON pin is at logic low level, the MOSFET is disabled. An internal pull down resistor to ground on the ON pin ensures that the MOSFET disables when not being driven.

#### **Power Sequencing**

The DML1010FDK device functions with any power sequence, but the output turn-on delay performance may vary from what is specified. To archive the specified performance, there are two recommended power sequences:

- 1.)  $V_{VBIAS} \rightarrow V_{IN} \rightarrow V_{ON}$
- 2.)  $V_{IN} \rightarrow V_{VBIAS} \rightarrow V_{ON}$

#### **Input Capacitor**

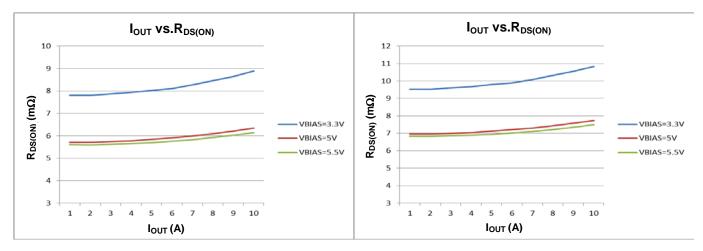
A capacitor of 10µF or higher value is recommended to be placed close to the IN pins of DML1010FDK. This capacitor can reduce the voltage drop caused by the in-rush current during the turn-on transient of the load switch. A higher value capacitor can be used to further reduce the voltage drop during high-current application.

#### **Output Capacitor**

A capacitor of 0.1µF or higher value is recommended to be placed between the OUT pins and GND. The switching times are affected by the capacitance. A larger capacitor makes the initial turn-on transient smoother. This capacitor must be large enough to supply a fast transient load in order to prevent the output from dropping.

#### VIN and VBIAS Voltage Range

For optimal on-resistance of load switch, make sure  $V_{IN} \le 1.5V + V_{VBIAS}$  and  $V_{VBIAS}$  is within the voltage range from 3.2V to 5.5V. On-resistance of load switch is higher if  $V_{IN} + 1.5V > V_{VBIAS}$ . Resistance curves of a typical sample device at different  $V_{VBIAS} = V_{IN}$  at  $I_{OUT} = -200$ mA are shown as below.





## **Application Information**

#### **Thermal Considerations**

To ensure proper operation, the maximum junction temperature of the DML1010FDK should not exceed +150°C. Several factors attribute to the junction temperate rise: load current, MOSFET on-resistance, junction-to-ambient thermal resistance, and ambient temperature. The maximum load current can be determined by:

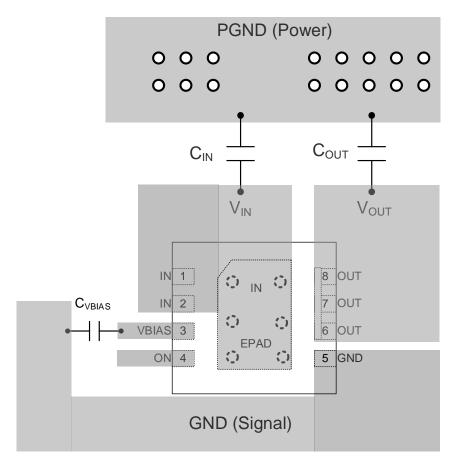
$$I_{LOAD(MAX)} = \sqrt{\frac{T_{J(MAX)} - T_{C}}{\Theta_{JC} \times R_{DS(ON)}}}$$

Where

- ILOAD(MAX) is the maximum allowable current on load (A). (6A for DML1010FDK)
- T<sub>J(MAX)</sub> is the maximum allowable junction temperature.
- T<sub>C</sub> is the case temperature of the device.
- $\Theta_{JC}$ = junction to case thermal impedance. This parameter is highly dependent upon PCB layout.

#### **PCB Layout Consideration**

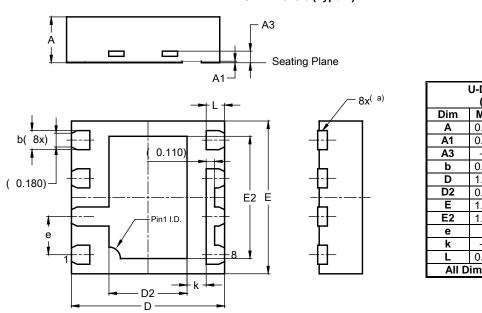
- 1. Place the input/output capacitors C<sub>IN</sub> and C<sub>OUT</sub> as close as possible to the IN and OUT pins.
- 2. The power traces which are IN trace, OUT trace, and GND trace should be short, wide, and directly for minimize parasitic inductance.
- 3. Place C<sub>VBIAS</sub> capacitor near the device pin.
- 4. Connect the signal ground to the GND pin, and keep a single connection from GND pin to the power ground behind the input or output capacitors.
- 5. For better power dissipation, via holes are recommended to connect the exposed pad's landing area to a large copper polygon on the other side of the printed circuit board. The copper polygons and exposed pad shall connect to IN pin on the printed circuit board.





## Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

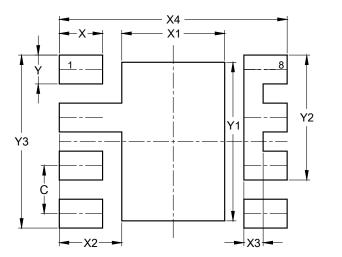


U-DFN2020-8							
(Type K)							
Dim	Тур						
Α	0.55	0.65	0.60				
A1	0.00	0.05	0.02				
A3	-	_	0.152				
b	0.20	0.30	0.25				
D	1.95	2.05	2.00				
D2	0.92	1.12	1.02				
Е	1.95	2.05	2.00				
E2	1.50	1.70	1.60				
е		0.50 B	SC				
k		_	0.25				
L	0.19	0.29	0.24				
All Dimensions in mm							

a) Actual shape depending upon manufacturing technology used.

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)		
С	0.500		
Х	0.450		
X1	1.070		
X2	0.650		
X3	0.200		
X4	2.370		
Y	0.300		
Y1	1.650		
Y2	1.300		
Y3	1.800		

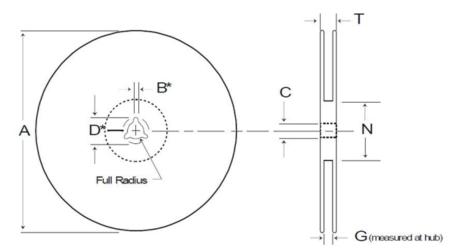
#### U-DFN2020-8 (Type K)

U-DFN2020-8 (Type K)



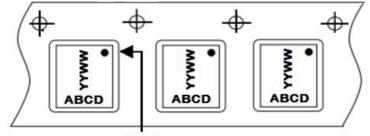
## Surface Mount Reel Specifications (All dimensions in mm)

#### DML1010FDK-7



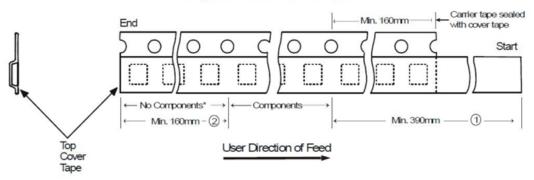
<sup>\*</sup> Drive spokes optional. If used, dimensions with asterisks apply.

Tape Size	A Max	B* Max	с	D* Max	N Min	G	T Max
8mm	178 ±2	2.0 +0.5 -0	13 +0.5 -0.2	20.5 ±0.2	55 ±5	8.4 +1.5 -0.0	14.4



Pin 1

### **Tape Leader and Trailer**



- Notes: 1. There shall be a leader of 230mm [9.05 inches] minimum which may consist of carrier and/or cover tape or a start tape followed by a minimum of 160mm [6.30 inches] of empty carrier tape sealed with cover tape.
  There shall be a trailer of 160mm [6.30 inches] minimum of empty carrier tape sealed with cover tape. The entire carrier tape must
  - There shall be a trailer of 160mm [6.30 inches] minimum of empty carrier tape sealed with cover tape. The entire carrier tape must release from the reel hub as the last portion of the tape unwinds from the reel without damage to the carrier tape and the remaining components in the cavities.



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